NSN 5961-01-228-5599

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View Online at https://aerobasegroup.com/nsn/5961-01-228-5599

| Inclosure | Material: |
|-----------|-----------|

Metal

Overall Length:

0.260 inches

Terminal Length:

0.250 inches

Overall Diameter:

0.335 inches

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Mounting Method:

Terminal

Terminal Circle Diameter:

0.200 inches

Features Provided:

Hermetically sealed case

Criticality Code Justification:

Feat

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

75.0 collector to base voltage/static/emitter open and 50.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open

Current Rating Per Characteristic:

800.00 milliamperes source cutoff current

Power Rating Per Characteristic:

3.0 watts small-signal input power, common-collector preset

Transfer Ratio:

300.0 static forward current transfer ratio, common-emitter

Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius junction

Special Features:

Nuclear hardness critical item; junction pattern arrangement: npn

Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

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